Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K15FS

High Speed Switching Applications Analog Switching Applications

• Compact package suitable for high-density mounting

• Low ON-resistance : $R_{on} = 4.0 \Omega \text{ (max)} \text{ (@V}_{GS} = 4 \text{ V)}$

: $R_{on} = 7.0 \Omega (max) (@V_{GS} = 2.5 V)$

Maximum Ratings (Ta = 25°C)

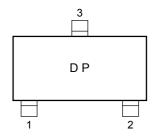
Characteristic		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	30	V	
Gate-Source voltage		V_{GSS}	±20	V	
Drain current	DC	I _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25°C)		P _D	100	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

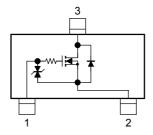
1. GATE 2. SOURCE 3. DRAIN SSM	
JEDEC —	
JEITA —	
TOSHIBA 2-2H	1B

Weight: 2.4 mg (typ.)

Marking







Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

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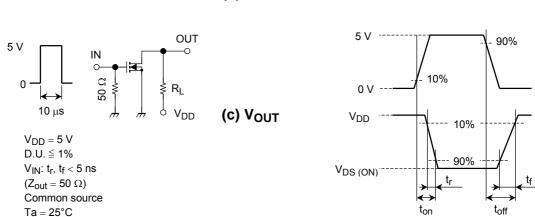
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	_	_	±1	μΑ
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	30	_	_	V
Drain Cut-off current		I _{DSS}	V _{DS} = 30 V, V _{GS} = 0	_	_	1	μА
Gate threshold voltage		V _{th}	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	8.0	_	1.5	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 \text{ V}, I_D = 10 \text{ mA}$	25	_	_	mS
Drain-Source ON resistance		R _{DS} (ON)	$I_D = 10 \text{ mA}, V_{GS} = 4 \text{ V}$	_	2.2	4.0	Ω
			$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$	_	4.0	7.0	
Input capacitance		C _{iss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	7.8	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.6	_	pF
Output capacitance		Coss	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	8.8	_	pF
Switching time	Turn-on time	t _{on}	V _{DD} = 5 V, I _D = 10 mA, V _{GS} = 0~5 V	_	50	_	- ns
	Turn-off time	t _{off}			180	_	

Switching Time Test Circuit



(b) V_{IN}



Precaution

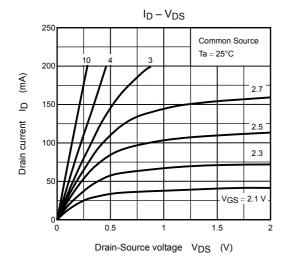
 V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 100 μA for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

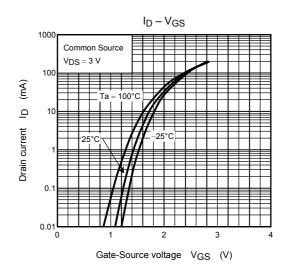
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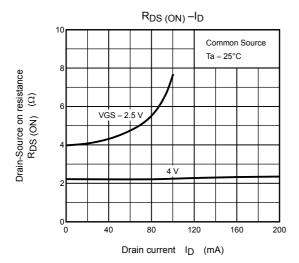
(relationship can be established as follows: $V_{\rm GS}$ (off) < $V_{\rm th}$ < $V_{\rm GS}$ (on))

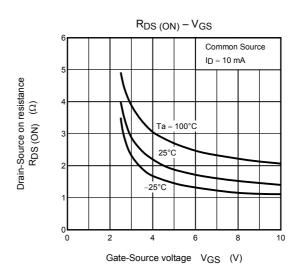
Please take this into consideration for using the device.

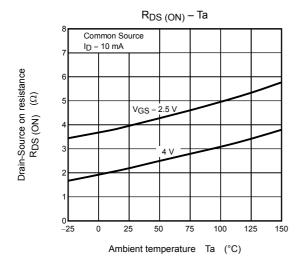
VGS recommended voltage of 2.5 V or higher to turn on this product.

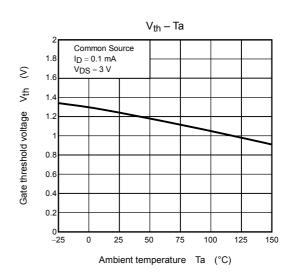


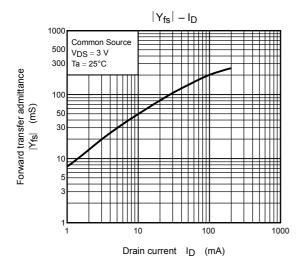


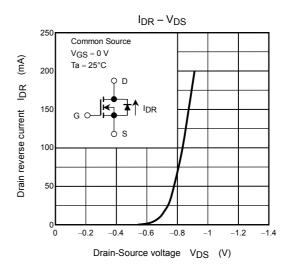


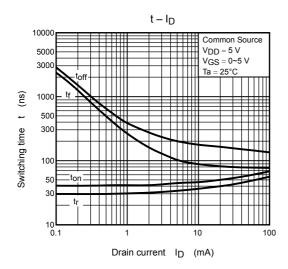


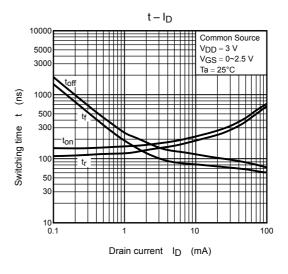


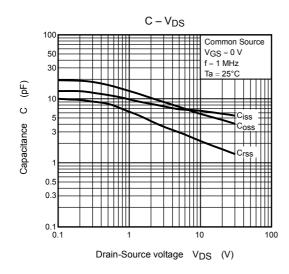


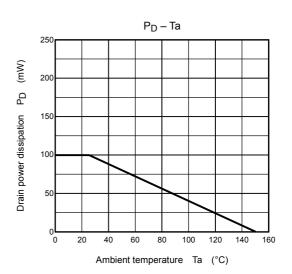












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RESTRICTIONS ON PRODUCT USE

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- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
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